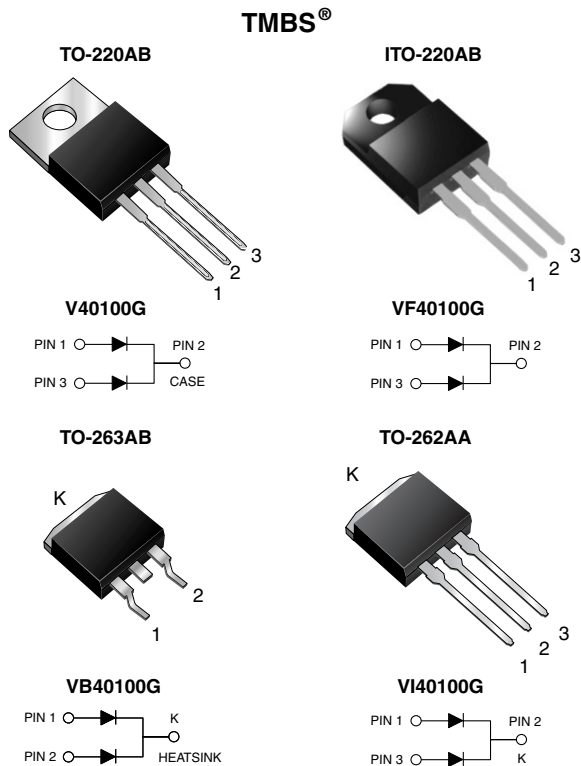


## Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.42\text{ V}$  at  $I_F = 5\text{ A}$



### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB, ITO-220AB and TO-262AA package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for commercial grade, meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 20 A
$V_{RRM}$	100 V
$I_{FSM}$	200 A
$V_F$ at $I_F = 20\text{ A}$	0.67 V
$T_J$ max.	150 °C

### MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V40100G	VF40100G	VB40100G	VI40100G	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	100				V
Maximum average forward rectified current (Fig. 1)	$I_{F(AV)}$	40 20				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	200				A
Isolation voltage (ITO-220AB only) From terminal to heatsink $t = 1\text{ min}$	$V_{AC}$	1500				V
Operating junction and storage temperature	$T_J, T_{STG}$	- 40 to + 150				°C

ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown Voltage	at I <sub>R</sub> = 1.0	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	100 (minimum)	-	V
Instantaneous forward voltage per diode <sup>(1)</sup>	at I <sub>F</sub> = 5 A I <sub>F</sub> = 10 A I <sub>F</sub> = 20 A	T <sub>A</sub> = 25 °C	V <sub>F</sub>	0.49 0.59 0.75	- - 0.81	
	at I <sub>F</sub> = 5 A I <sub>F</sub> = 10 A I <sub>F</sub> = 20 A	T <sub>A</sub> = 125 °C		0.42 0.54 0.67	- - 0.73	
Reverse current per diode <sup>(2)</sup>	at V <sub>R</sub> = 70 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>	12 8	- -	μA mA
	at V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C		55 21	500 35	μA mA

**Notes:**

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: 10 ms pulse width

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	V40100G	VF40100G	VB40100G	VI40100G	UNIT
Typical thermal resistance per diode	R <sub>θJC</sub>	2.0	5.0	2.0	2.0	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V40100G-E3/4W	1.88	4W	50/tube	Tube
ITO-220AB	VF40100G-E3/4W	1.75	4W	50/tube	Tube
TO-263AB	VB40100G-E3/4W	1.39	4W	50/tube	Tube
TO-263AB	VB40100G-E3/8W	1.39	8W	800/reel	Tape and reel
TO-262AA	VI40100G-E3/4W	1.46	4W	50/tube	Tube

### RATINGS AND CHARACTERISTICS CURVES

(T<sub>A</sub> = 25 °C unless otherwise noted)

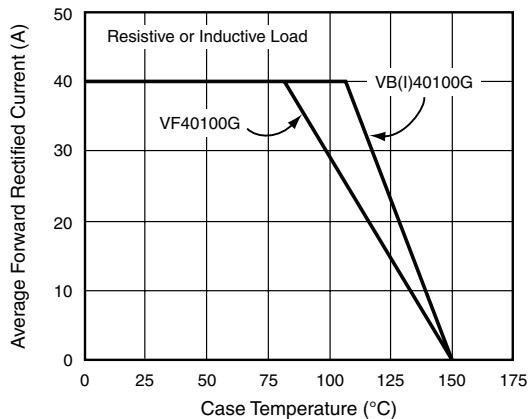


Figure 1. Maximum Forward Current Derating Curve

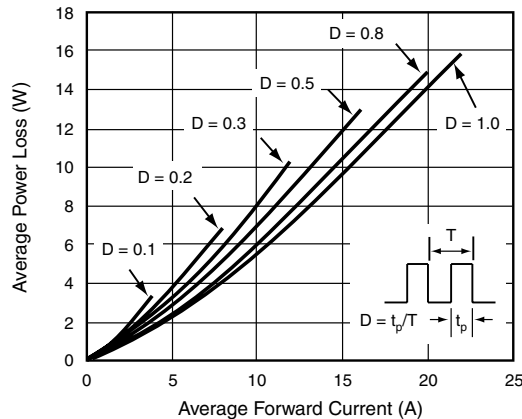


Figure 2. Forward Power Loss Characteristics



New Product  
V40100G, VF40100G, VB40100G & VI40100G

Vishay General Semiconductor

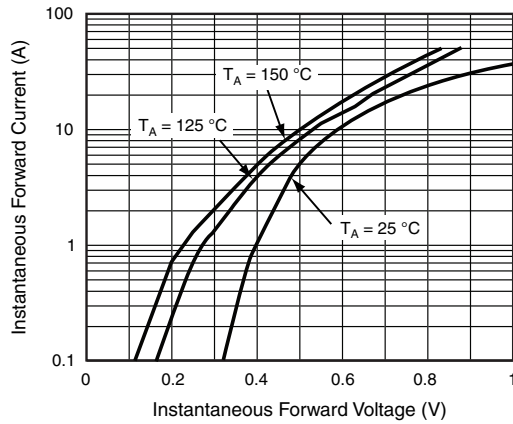


Figure 3. Typical Instantaneous Forward Characteristics

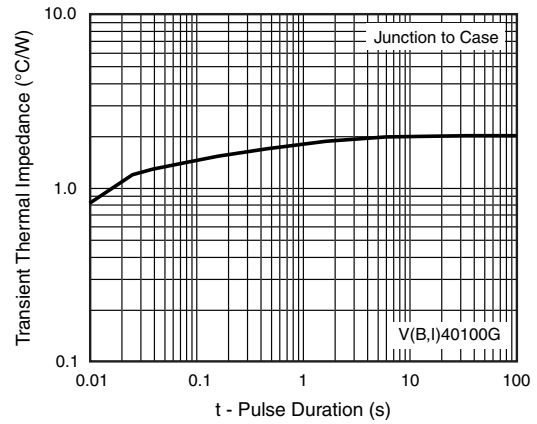


Figure 6. Typical Transient Thermal Impedance

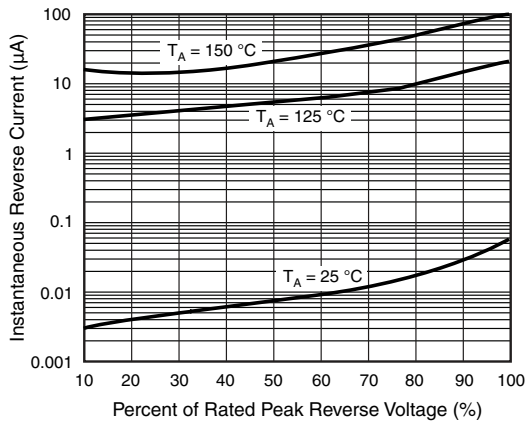


Figure 4. Typical Reverse Characteristics

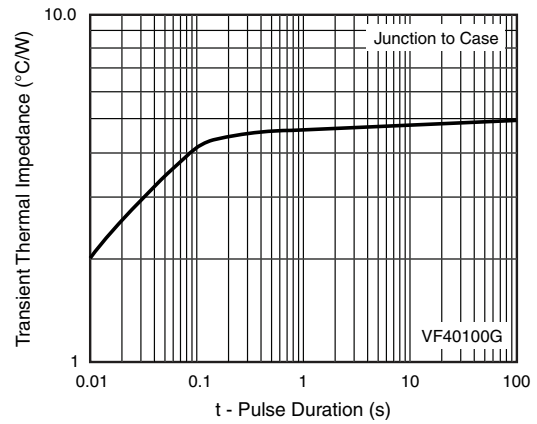


Figure 7. Typical Transient Thermal Impedance

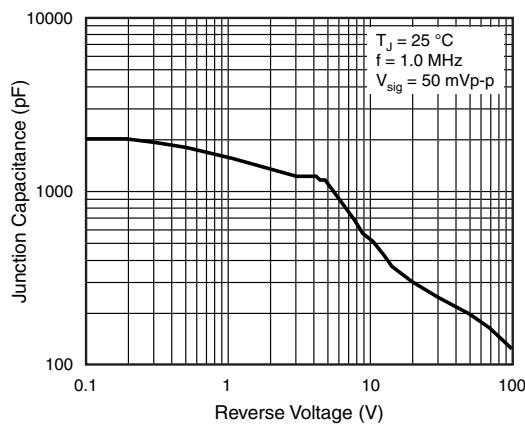


Figure 5. Typical Junction Capacitance





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